

**NPN-Silizium-Fototransistor im SMT TOPLED®-Gehäuse**  
**Silicon NPN Phototransistor in SMT TOPLED®-Package**  
**Lead (Pb) Free Product - RoHS Compliant**

**SFH 320**  
**SFH 320 FA**



SFH 320



SFH 320 FA

**Wesentliche Merkmale**

- Speziell geeignet für Anwendungen im Bereich von 450 nm bis 1150 nm (SFH 320) und 750 nm bis 1120 nm (SFH 320 FA)
- Hohe Linearität
- P-LCC-2 Gehäuse
- Gruppiert lieferbar
- Für alle Lötverfahren geeignet.

**Features**

- Especially suitable for applications from 450 nm to 1150 nm (SFH 320) and 750 nm to 1120 nm (SFH 320 FA)
- High linearity
- P-LCC-2 package
- Available in groups
- Suitable for all soldering methods.

**Anwendungen**

- Miniaturlichtschranken für Gleich- und Wechsellichtbetrieb
- Industrieelektronik
- „Messen/Steuern/Regeln“

**Applications**

- Miniature photointerrupters
- Industrial electronics
- For control and drive circuits

Typ Type	Bestellnummer Ordering Code	Fotostrom , ( $E_e=0,1\text{mW/cm}^2, \lambda=950\text{nm } V_{CE} = 5\text{ V}$ ) Photocurrent $I_{pce}$ ( $\mu\text{A}$ )
SFH 320	Q65110A2471	> 16
SFH 320-3	Q65110A2469	25-50
SFH 320-3/-4	Q65110A1781	25-80
SFH 320-4	Q65110A2510	40-80
SFH 320 FA	Q65110A2472	> 16
SFH 320 FA-3	Q65110A2470	25-50
SFH 320 FA-3/-4	Q65110A2475	25-80
SFH 320 FA-4	Q65110A1836	40-80

**Grenzwerte**  
**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}; T_{stg}$	- 40 ... + 100	°C
Kollektor-Emitterspannung Collector-emitter voltage	$V_{CE}$	35	V
Kollektorstrom Collector current	$I_C$	15	mA
Kollektorspitzenstrom, $\tau < 10 \mu s$ Collector surge current	$I_{CS}$	75	mA
Verlustleistung, $T_A = 25 \text{ °C}$ Total power dissipation	$P_{tot}$	165	mW
Wärmewiderstand für Montage auf PC-Board Thermal resistance for mounting on pcb	$R_{thJA}$	450	K/W

Kennwerte ( $T_A = 25\text{ °C}$ ,  $\lambda = 950\text{ nm}$ )

## Characteristics

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit
		SFH 320	SFH 320 FA	
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S\text{ max}}$	980	980	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von $S_{\text{max}}$ Spectral range of sensitivity $S = 10\%$ of $S_{\text{max}}$	$\lambda$	450 ... 1150	750 ... 1120	nm
Bestrahlungsempfindliche Fläche ( $\varnothing 220\text{ }\mu\text{m}$ ) Radiant sensitive area	$A$	0.038	0.038	$\text{mm}^2$
Abmessung der Chipfläche Dimensions of chip area	$L \times B$ $L \times W$	$0.45 \times 0.45$	$0.45 \times 0.45$	$\text{mm} \times \text{m}$ m
Halbwinkel Half angle	$\varphi$	$\pm 60$	$\pm 60$	Grad deg.
Kapazität, $V_{\text{CE}} = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$ Capacitance	$C_{\text{CE}}$	5.0	5.0	pF
Dunkelstrom Dark current $V_{\text{CE}} = 20\text{ V}$ , $E = 0$	$I_{\text{CEO}}$	1 ( $\leq 50$ )	1 ( $\leq 50$ )	nA

Die Fototransistoren werden nach ihrer Fotoempfindlichkeit gruppiert und mit arabischen Ziffern gekennzeichnet.

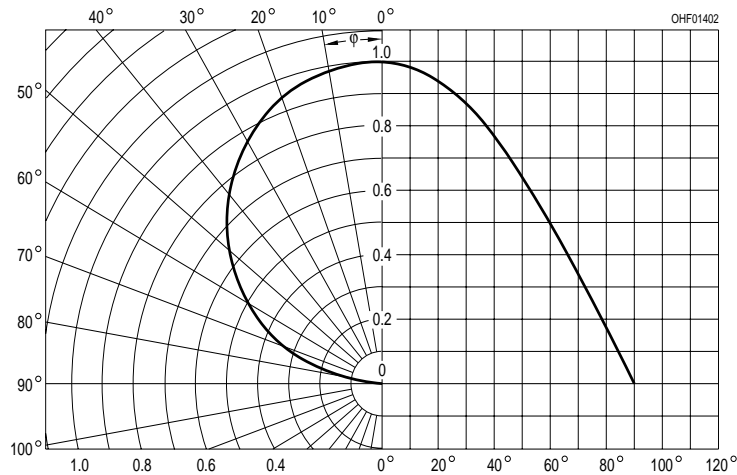
The phototransistors are grouped according to their spectral sensitivity and distinguished by arabian figures.

Bezeichnung Parameter	Symbol Symbol	Wert Value				Einheit Unit
		SFH 320 /FA	-2	-3	-4	
Fotostrom, $\lambda = 950 \text{ nm}$ Photocurrent $E_e = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	$I_{PCE}$	$\geq 16$	16 ... 32	25 ... 50	40 ... 80	$\mu\text{A}$
<b>SFH 320:</b> $E_v = 1000 \text{ lx}$ , Normlicht/standard light A, $V_{CE} = 5 \text{ V}$	$I_{PCE}$	–	420	650	1000	$\mu\text{A}$
Anstiegszeit/Abfallzeit Rise and fall time $I_C = 1 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	$t_r, t_f$	7	6	7	8	$\mu\text{s}$
Kollektor-Emitter-Sättigungsspannung Collector-emitter saturation voltage $I_C = I_{PCEmin}^{1)} \times 0.3,$ $E_e = 0.1 \text{ mW/cm}^2$	$V_{CEsat}$	150	150	150	150	mV

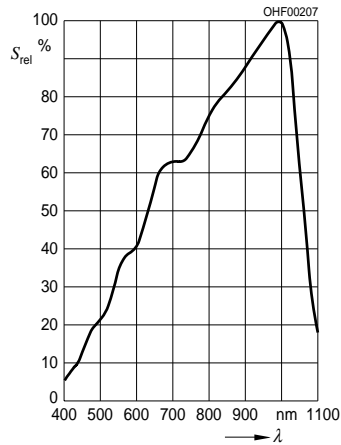
1)  $I_{PCEmin}$  ist der minimale Fotostrom der jeweiligen Gruppe.

1)  $I_{PCEmin}$  is the min. photocurrent of the specified group.

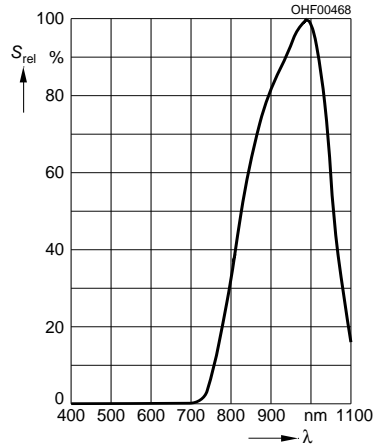
**Directional Characteristics  $S_{rel} = f(\varphi)$**



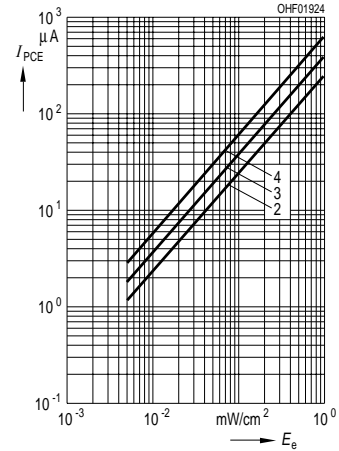
**Relative Spectral Sensitivity, SFH 320**  
 $S_{rel} = f(\lambda)$



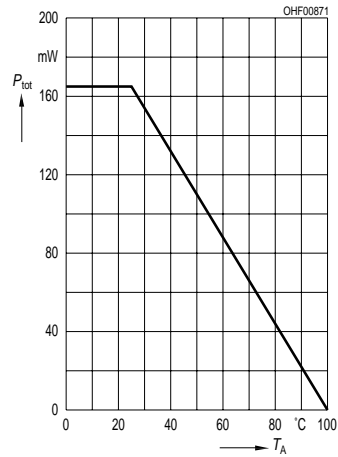
**Relative Spectral Sensitivity, SFH 320 FA**  
 $S_{rel} = f(\lambda)$



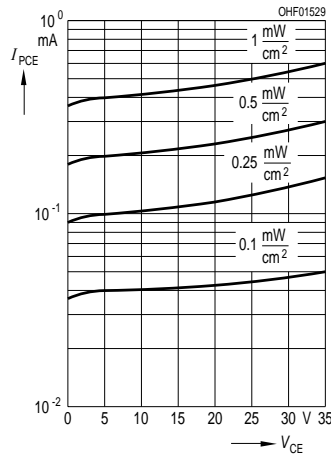
**Photocurrent**  
 $I_{PCE} = f(E_e), V_{CE} = 5 V$



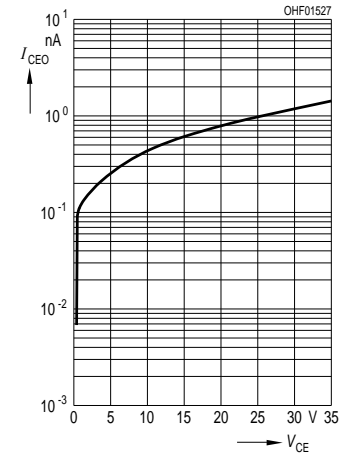
**Total Power Dissipation**  
 $P_{tot} = f(T_A)$



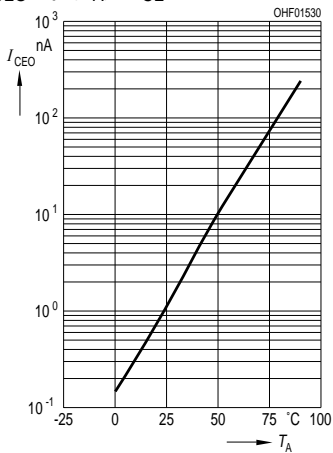
**Photocurrent**  
 $I_{PCE} = f(V_{CE}), E_e = \text{Parameter}$



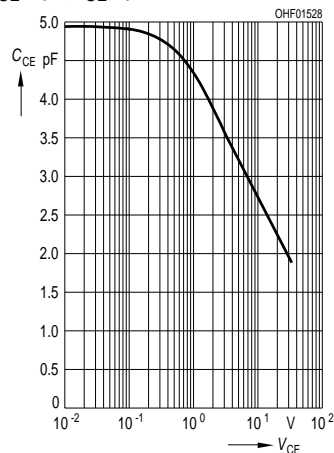
**Dark Current**  
 $I_{CEO} = f(V_{CE}), E = 0$



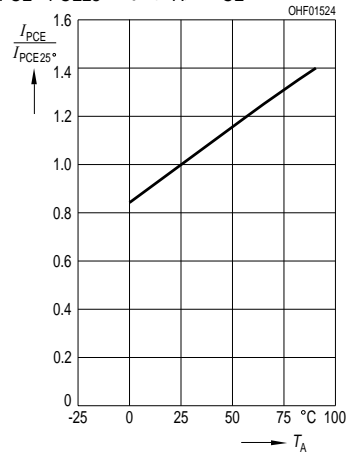
**Dark Current**  
 $I_{CEO} = f(T_A), V_{CE} = 5 V, E = 0$



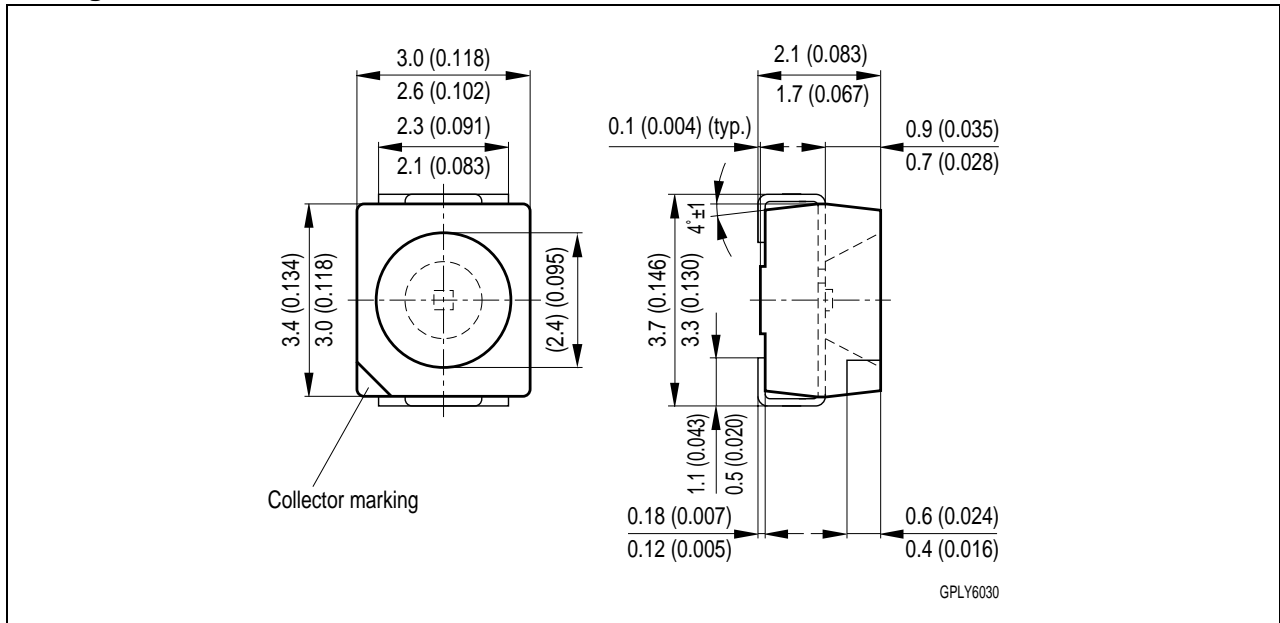
**Capacitance**  
 $C_{CE} = f(V_{CE}), f = 1 \text{ MHz}, E = 0$



**Photocurrent**  
 $I_{PCE}/I_{PCE25^\circ} = f(T_A), V_{CE} = 5 V$

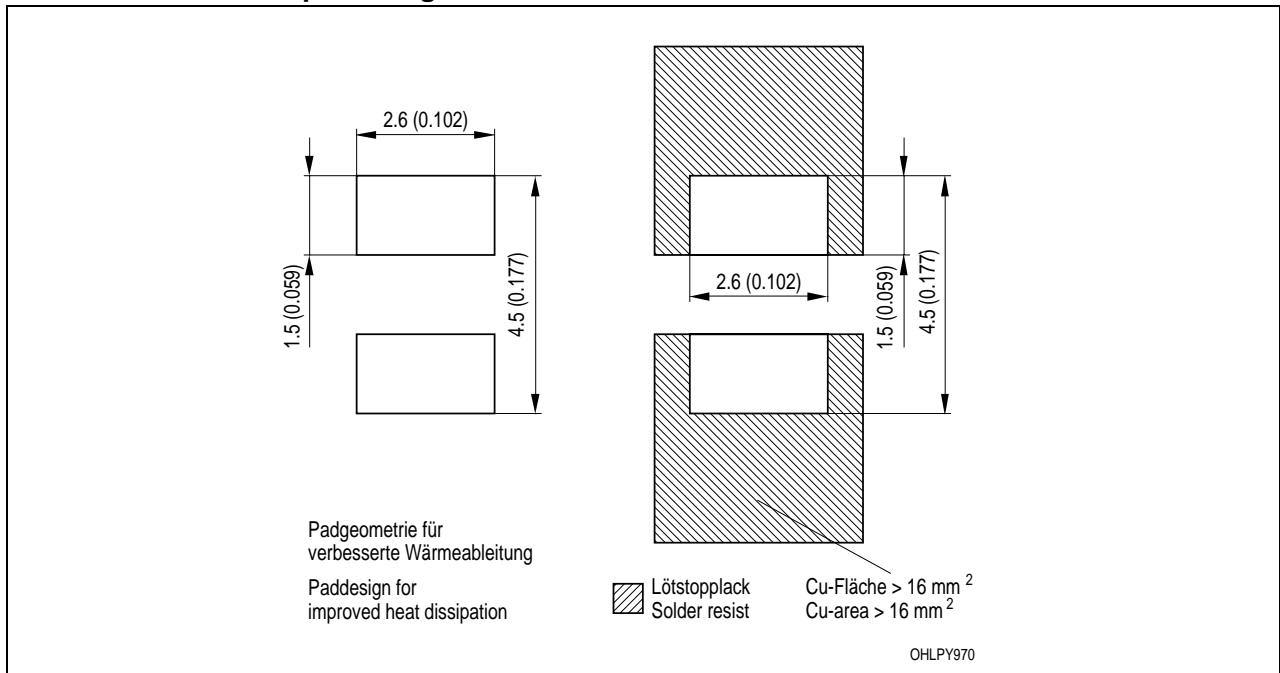


**Maßzeichnung  
Package Outlines**



Maße in mm (inch) / Dimensions in mm (inch).

**Empfohlenes Lötpaddesign  
Recommended Solderpad Design**



Maße in mm (inch) / Dimensions in mm (inch).

**Lötbedingungen**

**Soldering Conditions**

**Reflow Lötprofil für bleifreies Löt**

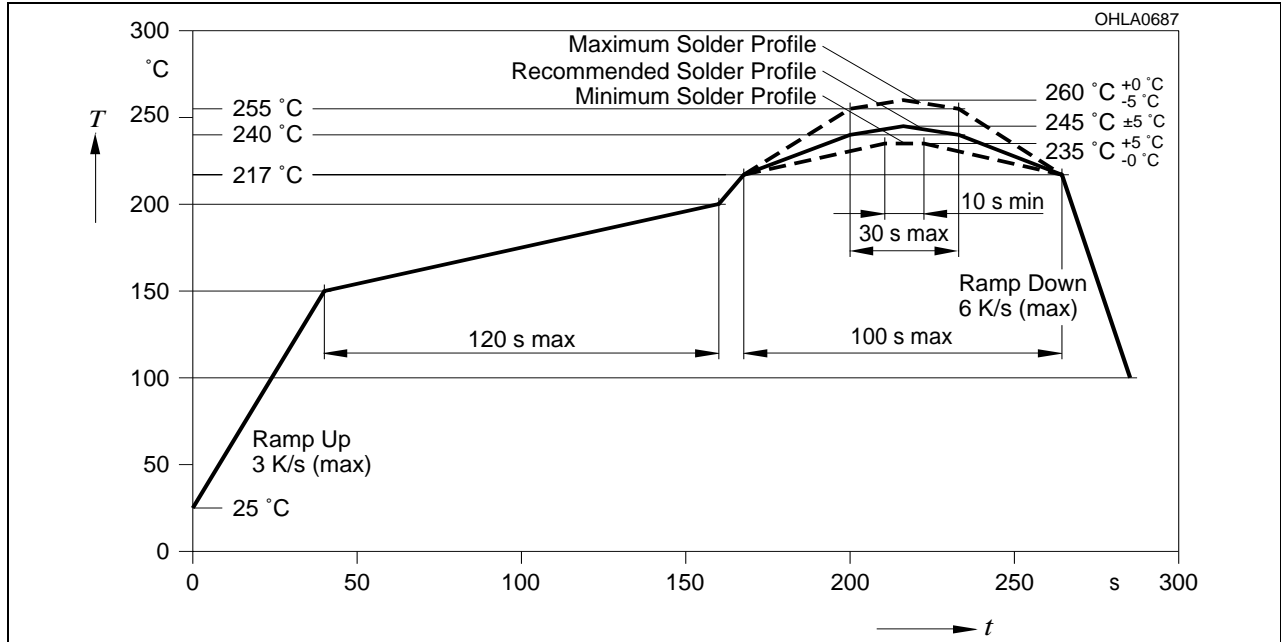
**Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 2

Preconditioning acc. to JEDEC Level 2

(nach J-STD-020C)

(acc. to J-STD-020C)

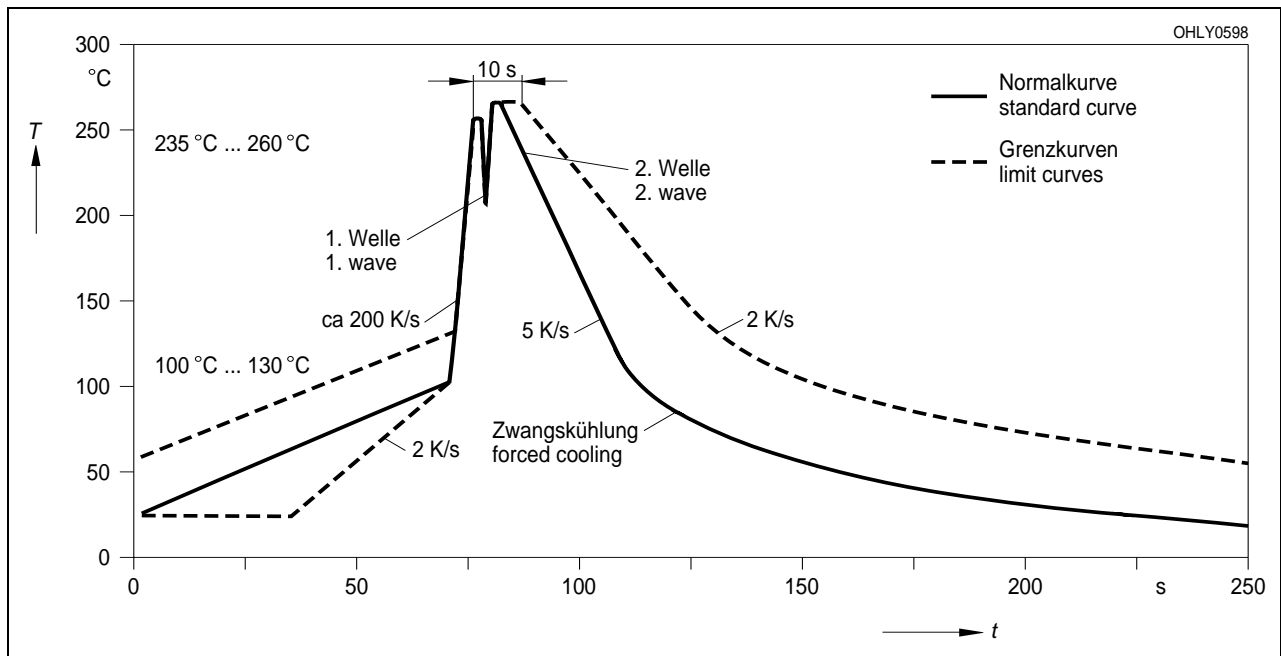


**Wellenlöt (TTW)**

(nach CECC 00802)

**TTW Soldering**

(acc. to CECC 00802)



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